IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of)
Bin Yu et al.) Oroup Art Unit: Unassigned
Application No.: Unassigned) Examiner: Unassigned
Filed: September 3, 2003)
Title: ADDITIONAL GATE CONTROL FOR A DOUBLE-GATE MOSFET)))

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. § 1.97(b)

U.S. Patent and Trademark Office 2011 South Clark Place Customer Window Crystal Plaza Two, Lobby, Room 1B03 Arlington, Virginia 22202

Sir:

Pursuant to 37 C.F.R. §§ 1.56 and 1.97(b), Applicant(s) bring to the attention of the Examiner the documents listed on the attached PTO 1449. This Information Disclosure Statement is being filed before the mailing date of a first Office Action in the above-referenced application. As such, no certification or fee is required. Copies of the listed documents, except for U.S. Patents and patent application publications, are attached.

Applicant(s) respectfully request(s) that the Examiner consider the listed documents and indicate that they were considered by making appropriate notations on the attached form.

If any copending application(s) is/are cited on the attached PTO 1449, the Examiner's attention is directed to the foregoing application(s) in compliance with § 2001.06(b) of the Manual of Patent Examining Procedure. By identifying the copending application(s), the assignee and/or applicant of the application(s) do not waive confidentiality of the application(s). Accordingly, the U.S. Patent and Trademark Office is requested to maintain the confidentiality of the copending application(s) under 35 U.S.C. § 122.

This submission does not represent that a search has been made and does not constitute an admission that each or all of the listed documents are material or constitute "prior art." If the Examiner applies any of the documents as prior art against any claim in the application and Applicant(s) determine(s) that the cited document(s) do not constitute "prior art" under United States law, Applicant(s) reserve(s) the right to present to the Office the relevant facts and law regarding the appropriate status of such documents.

Applicant(s) further reserve(s) the right to take appropriate action to establish the patentability of the disclosed invention over the listed documents, should one or more of the documents be applied against the claims of the present application.

If there is any fee due in connection with the filing of this Statement, please charge the fee to our Deposit Account No. 50-1070.

Respectfully submitted,

HARRITY & SNYDER, L.L.P.

Bv:

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Customer Number: 26615

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INFORMATION DISCLOSURE CITATION

EXAMINER

Customer Number: 26615

ATTORNEY'S DKT No. APPLICATION NO. H1492 Unassigned APPLICANT(S) Bin Yu et al. FILING DATE GROUP September 3, 2003 Unassigned

PTO-1449										
U.S. PATENT DOCUMENTS										
EXAMINER'S INITIALS	PATENT NO.	PATENT NO. DATE NAME		CLASS	SUBCLASS	FILING DATE				
	6,525,403 B2	02-25-03	Inaba et al.		257	618	09-24-01/			
	6,433,609 B1	08-13-02	Voldman		327	313	11-19-01			
FOREIGN PATENT DOCUMENTS										
EXAMINER'S INITIALS	PATENT NO.	DATE	COUNT	RY	CLASS	SUBCLASS	Trans Yes	No.		
	Digh Hisamoto IEEE Transactio 2325. Yang-Kyu Choi Pages 421-424 Xuejue Huang e Devices, Vol. 4 Yang-Kyu Choi Device Letters, Xuejue Huang e Co-pending App	et al.: "Finf ns on Electr et al.: "Sub- et al.: "Sub- 8, No. 5, M et al.: "Nar Vol. 23, No et al.: "Sub- blication Ser	cluding Author, Tit ET - A Self-Aligne on Devices, Vol. 4 0-20nm CMOS Fin 50 nm P-Channel ay 2001, pages 88 noscale CMOS Spa . 1, January 2002 50-nm FinFET: PM ial No. 10/348,758	d Double-Gate 7, No. 12, De FET Technolo Fin FET," IEEE 30-886. cer FinFET for , pages 25-27 10S," 1999 IE 8, filed Januar	e MOSFE cember 2 gies," 20 Transac the Tera EE, IEDM y 23, 20	Scalable to 2000, pages O1 IEEE, IED tions on Elect bit Era," IEE , pages 67-7	2320- M, tron E Elect			
	specification, 2 Co-pending App AND TRIPLE GA specification, 1 Co-pending App AND GATE ARC specification, 1 U.S. Patent App	9 sheets of oblication Ser ATE MOSFE 2 sheets of oblication Ser DUND MOSF 8 sheets of oblication Publication Publi	ial No. 10/274,96 T DEVICES AND M drawings. ial No. 10/348,91 FET DEVICES AND	1, filed Octobe IETHODS FOR 1, filed Januar METHODS FO	er 22, 20 MAKING y 23, 20 DR MAKII	02, entitled is SAME," 15 03, entitled NG SAME,"	"DOUB page "TRI-G 17 pag	ATE le t al.		

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant(s).

DATE CONSIDERED